

## General Description

The AO6800 uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a load switch or in PWM applications.

## Features

$V_{DS}$  (V) = 30V

$I_D$  = 3.4 A

$R_{DS(ON)} < 60\text{m}\Omega$  ( $V_{GS} = 10\text{V}$ )

$R_{DS(ON)} < 75\text{m}\Omega$  ( $V_{GS} = 4.5\text{V}$ )

$R_{DS(ON)} < 115\text{m}\Omega$  ( $V_{GS} = 2.5\text{V}$ )



### Absolute Maximum Ratings $T_A=25^\circ\text{C}$ unless otherwise noted

Parameter	Symbol	Maximum	Units
Drain-Source Voltage	$V_{DS}$	30	V
Gate-Source Voltage	$V_{GS}$	$\pm 12$	V
Continuous Drain Current <sup>A</sup>	$I_D$	3.4	A
$T_A=70^\circ\text{C}$		2.7	
Pulsed Drain Current <sup>B</sup>	$I_{DM}$	20	
Power Dissipation <sup>A</sup>	$P_D$	1.15	W
$T_A=70^\circ\text{C}$		0.73	
Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 to 150	°C

### Thermal Characteristics each FET

Parameter	Symbol	Typ	Max	Units
Maximum Junction-to-Ambient <sup>A</sup>	$R_{\theta JA}$	78	110	°C/W
Steady-State		106	150	°C/W
Maximum Junction-to-Lead <sup>C</sup>	$R_{\theta JL}$	64	80	°C/W

**Electrical Characteristics ( $T_J=25^\circ\text{C}$  unless otherwise noted)**

Symbol	Parameter	Conditions	Min	Typ	Max	Units
<b>STATIC PARAMETERS</b>						
$\text{BV}_{\text{DSS}}$	Drain-Source Breakdown Voltage	$I_D=250\mu\text{A}, V_{GS}=0\text{V}$	30			V
$I_{\text{DSS}}$	Zero Gate Voltage Drain Current	$V_{DS}=24\text{V}, V_{GS}=0\text{V}$	$T_J=55^\circ\text{C}$	1	5	$\mu\text{A}$
$I_{\text{GSS}}$	Gate-Body leakage current	$V_{DS}=0\text{V}, V_{GS}=\pm 12\text{V}$			100	nA
$V_{\text{GS(th)}}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=250\mu\text{A}$	0.6	1	1.4	V
$I_{\text{D(ON)}}$	On state drain current	$V_{GS}=4.5\text{V}, V_{DS}=5\text{V}$	20			A
$R_{\text{DS(ON)}}$	Static Drain-Source On-Resistance	$V_{GS}=10\text{V}, I_D=3.4\text{A}$	$T_J=125^\circ\text{C}$	50	60	$\text{m}\Omega$
		$V_{GS}=4.5\text{V}, I_D=3\text{A}$		66	80	
		$V_{GS}=2.5\text{V}, I_D=2\text{A}$		60	75	
$g_{\text{FS}}$	Forward Transconductance	$V_{DS}=5\text{V}, I_D=3\text{A}$		7.8		S
$V_{\text{SD}}$	Diode Forward Voltage	$I_S=1\text{A}, V_{GS}=0\text{V}$		0.8	1	V
$I_S$	Maximum Body-Diode Continuous Current				1.5	A
<b>DYNAMIC PARAMETERS</b>						
$C_{\text{iss}}$	Input Capacitance	$V_{GS}=0\text{V}, V_{DS}=15\text{V}, f=1\text{MHz}$		390		pF
$C_{\text{oss}}$	Output Capacitance			54.5		pF
$C_{\text{rss}}$	Reverse Transfer Capacitance			41		pF
$R_g$	Gate resistance	$V_{GS}=0\text{V}, V_{DS}=0\text{V}, f=1\text{MHz}$		3		$\Omega$
<b>SWITCHING PARAMETERS</b>						
$Q_g$	Total Gate Charge	$V_{GS}=4.5\text{V}, V_{DS}=15\text{V}, I_D=3.4\text{A}$		4.96		nC
$Q_{\text{gs}}$	Gate Source Charge			0.8		nC
$Q_{\text{gd}}$	Gate Drain Charge			1.72		nC
$t_{\text{D(on)}}$	Turn-On Delay Time	$V_{GS}=10\text{V}, V_{DS}=15\text{V}, R_L=4.7\Omega, R_{\text{GEN}}=6\Omega$		6.8		ns
$t_r$	Turn-On Rise Time			3.6		ns
$t_{\text{D(off)}}$	Turn-Off Delay Time			35.2		ns
$t_f$	Turn-Off Fall Time			13.7		ns
$t_{\text{rr}}$	Body Diode Reverse Recovery Time	$I_F=3.4\text{A}, dI/dt=100\text{A}/\mu\text{s}$		11.4		ns
$Q_{\text{rr}}$	Body Diode Reverse Recovery Charge	$I_F=3.4\text{A}, dI/dt=100\text{A}/\mu\text{s}$		6		nC

A: The value of  $R_{\text{0JA}}$  is measured with the device mounted on 1in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with  $T_A=25^\circ\text{C}$ . The value in any given application depends on the user's specific board design. The current rating is based on the  $t \leq 10\text{s}$  thermal resistance rating.

B: Repetitive rating, pulse width limited by junction temperature.

C. The  $R_{\text{0JA}}$  is the sum of the thermal impedance from junction to lead  $R_{\text{0JL}}$  and lead to ambient.

D. The static characteristics in Figures 1 to 6,12,14 are obtained using 80 $\mu\text{s}$  pulses, duty cycle 0.5% max.

E. These tests are performed with the device mounted on 1 in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with  $T_A=25^\circ\text{C}$ . The SOA curve provides a single pulse rating.

## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

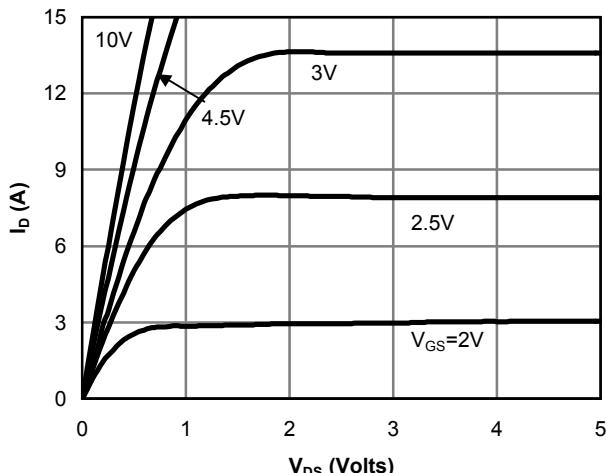


Fig 1: On-Region Characteristics

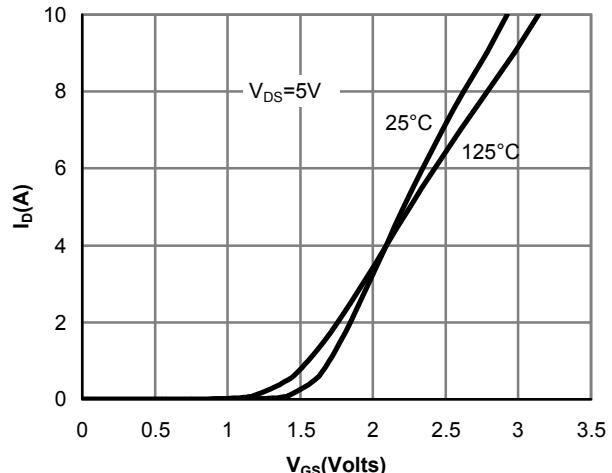


Figure 2: Transfer Characteristics

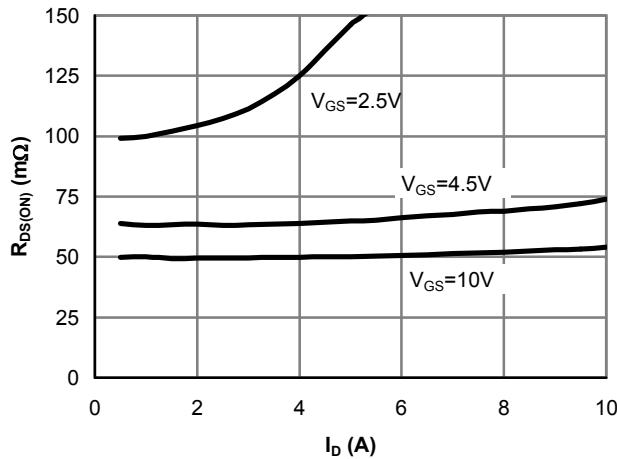


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

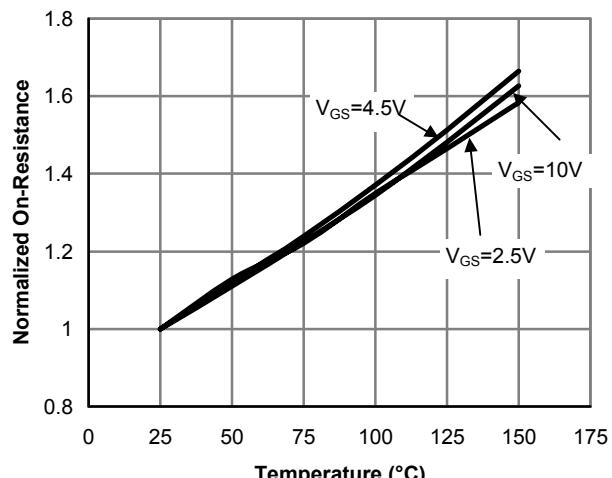


Figure 4: On-Resistance vs. Junction Temperature

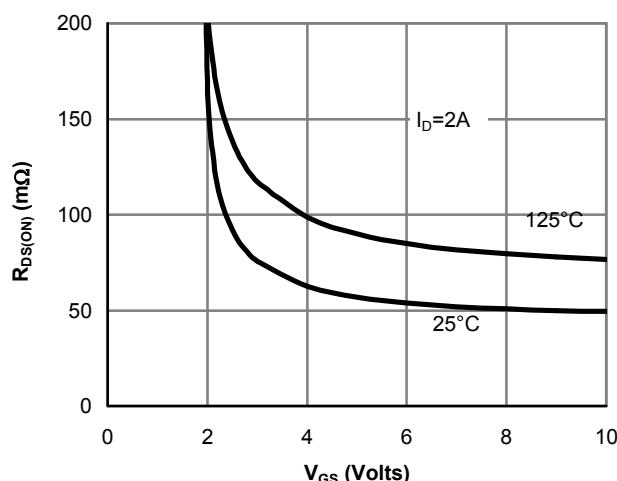


Figure 5: On-Resistance vs. Gate-Source Voltage

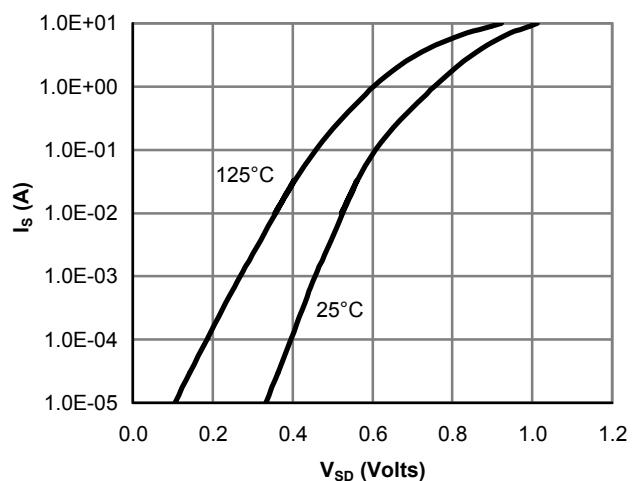


Figure 6: Body-Diode Characteristics

## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

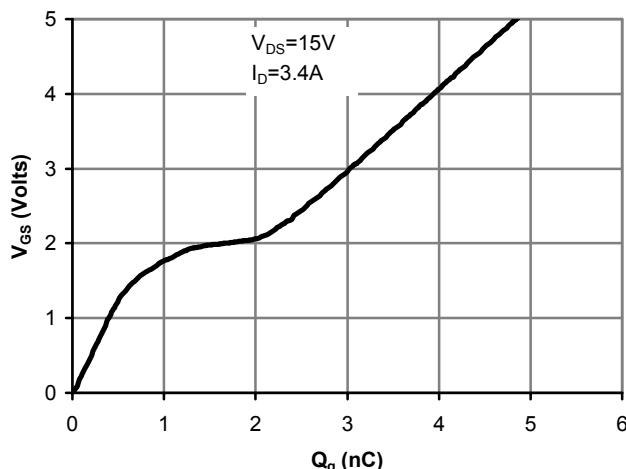


Figure 7: Gate-Charge Characteristics

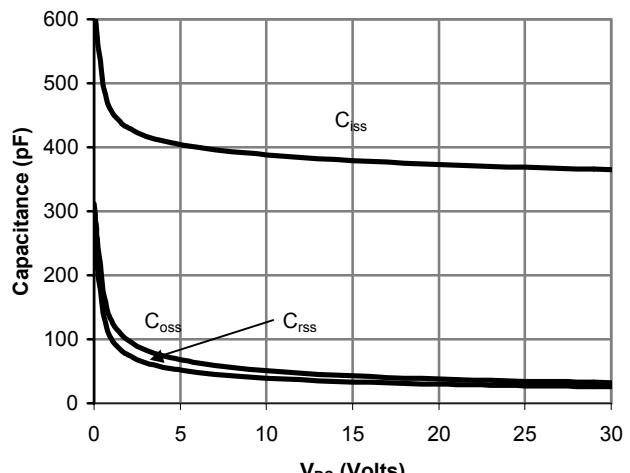


Figure 8: Capacitance Characteristics

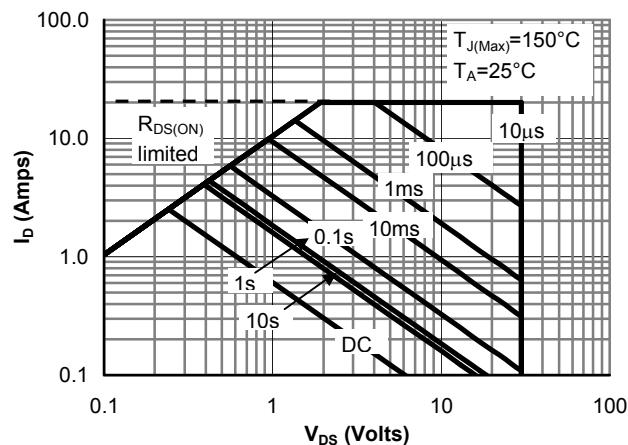


Figure 9: Maximum Forward Biased Safe Operating Area (Note E)

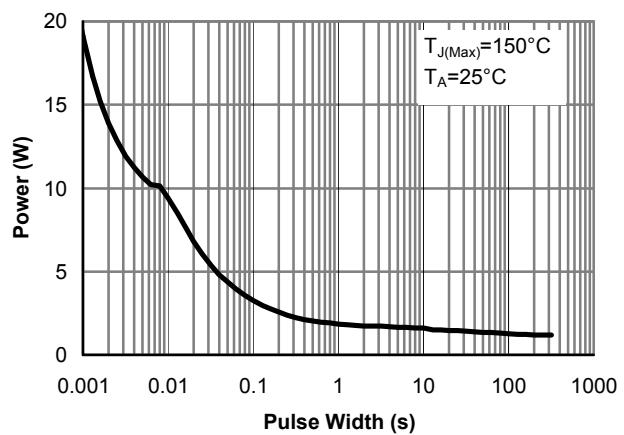


Figure 10: Single Pulse Power Rating Junction-to-Ambient (Note E)

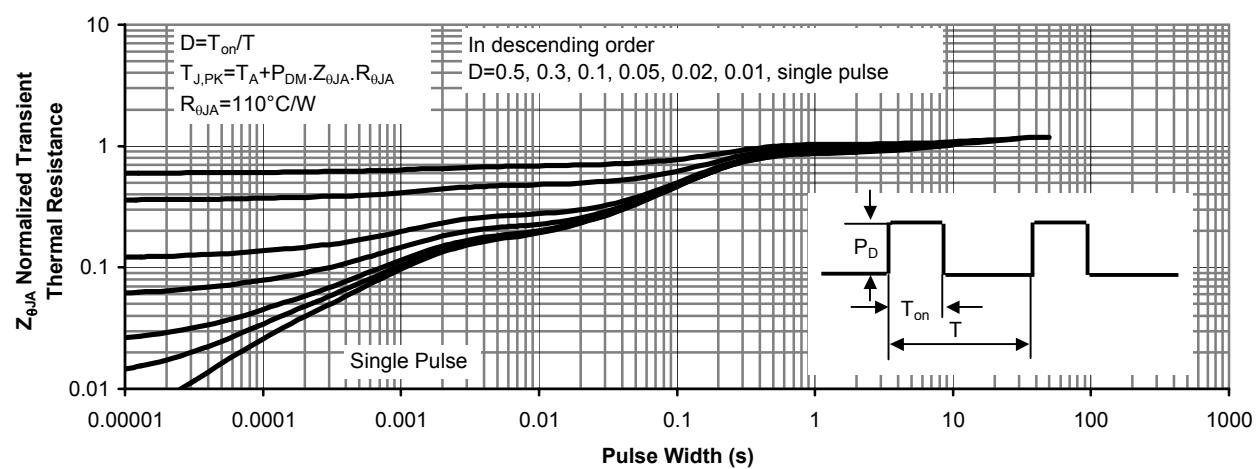
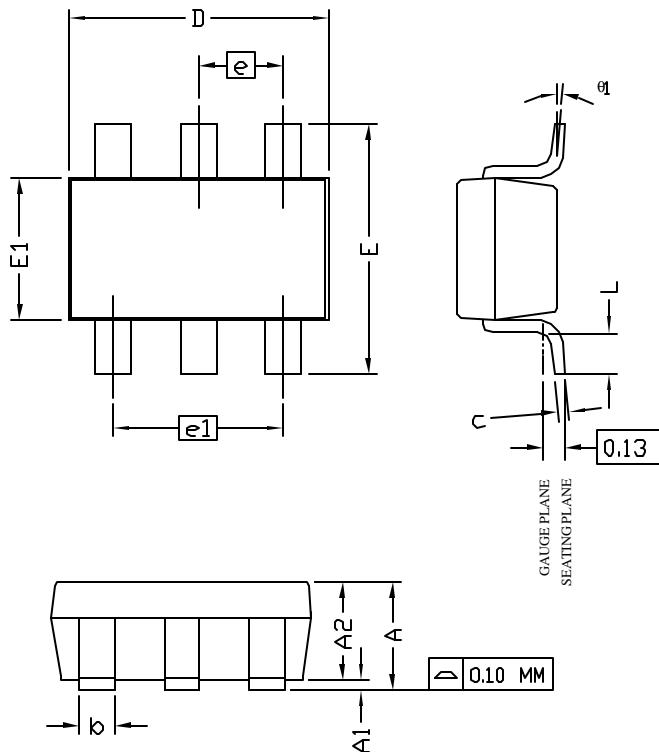


Figure 11: Normalized Maximum Transient Thermal Impedance



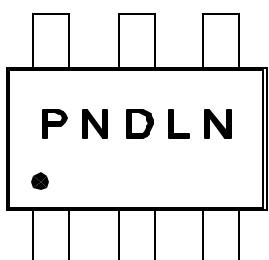
## TSOP-6 Package Data



SYMBOLS	DIMENSIONS IN MILLIMETERS		
	MIN	NOM	MAX
A	1.00	—	1.25
A1	0.00	—	0.10
A2	1.00	1.10	1.15
b	0.35	0.40	0.50
c	0.10	0.13	0.20
D	2.70	2.90	3.10
E	2.60	2.80	3.00
E1	1.60	1.80	2.00
e	0.95 BSC		
e1	1.90 BSC		
L	0.37	—	—
θ1	1°	5°	8°

NOTE:  
 1. LEAD FINISH: 150 MICROINCHES ( 3.8  $\mu$ m ) MIN.  
 THICKNESS OF Tin/Lead ( SOLDER ) PLATED ON LEAD  
 2. TOLERANCE  $\pm 0.100$  mm ( 4 mil ) UNLESS OTHERWISE  
 SPECIFIED  
 3. COPLANARITY : 0.100 mm  
 4. DIMENSION L IS MEASURED IN GAGE PLANE

### PACKAGE MARKING DESCRIPTION

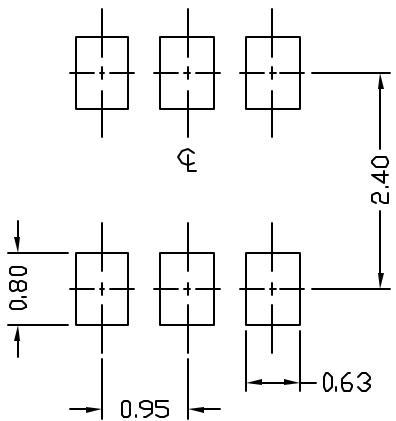


TSOP-6 PART NO. CODE

PART NO.	CODE
AO6800	H0

NOTE:  
 P N - PART NUMBER CODE.  
 D - YEAR AND WEEK CODE.  
 L N - ASSEMBLY LOT CODE, FAB AND  
 ASSEMBLY LOCATION CODE.

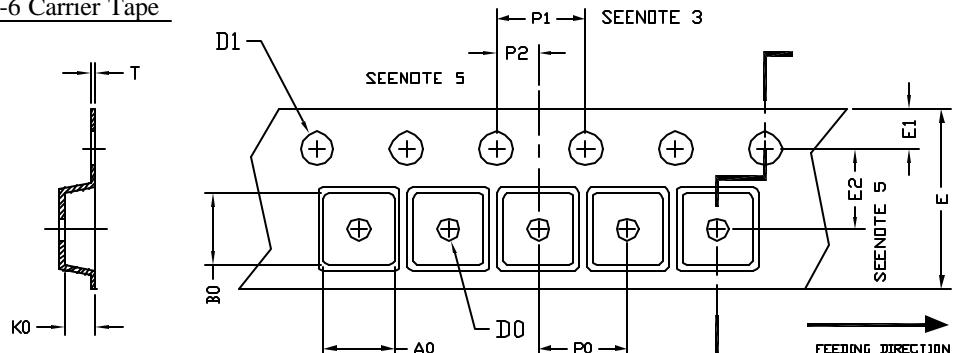
### RECOMMENDED LAND PATTERN





## TSOP-6 Tape and Reel Data

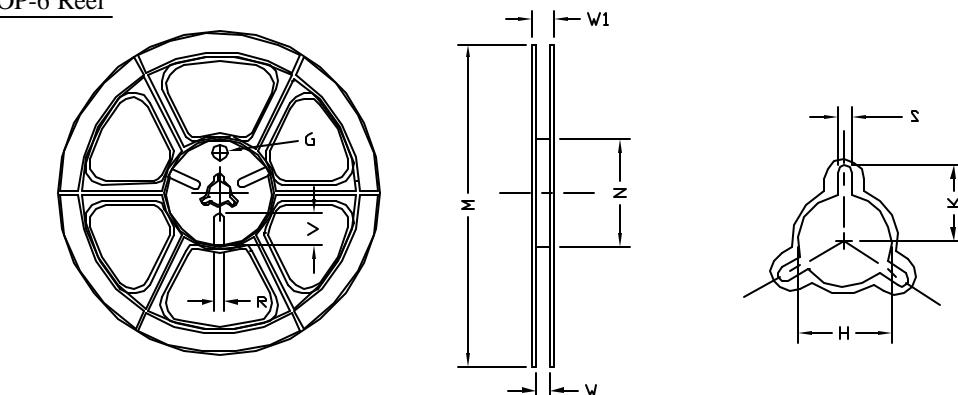
### TSOP-6 Carrier Tape



UNIT: MM

PACKAGE	$A_0$	$B_0$	$K_0$	$D_0$	$D_1$	$E$	$E_1$	$E_2$	$P_0$	$P_1$	$P_2$	$T$
SOT-23 (B mm)	3.15 $\pm 0.10$	3.27 $\pm 0.10$	1.34 $\pm 0.10$	1.10 $\pm 0.01$	1.50 $\pm 0.10$	8.00 $\pm 0.20$	1.75 $\pm 0.10$	3.50 $\pm 0.05$	4.00 $\pm 0.10$	4.00 $\pm 0.10$	2.00 $\pm 0.10$	0.25 $\pm 0.05$

### TSOP-6 Reel



UNIT: MM

TAPE SIZE	REEL SIZE	$M$	$N$	$W$	$W_1$	$H$	$K$	$S$	$G$	$R$	$V$
8 mm	$\phi 180$	$\phi 180.00$ $\pm 0.50$	$\phi 60.50$	9.00 $\pm 0.30$	11.40 $\pm 1.00$	$\phi 13.00$ $+0.50$ $-0.20$	10.60	2.00 $\pm 0.50$	$\phi 9.00$	5.00	18.00

### TSOP-6 Tape

Leader / Trailer  
& Orientation

